Photocouplers GaAlAs Infrared LED & Photo IC

# TLP2368

#### 1. Applications

- Factory Automation (FA)
- Plasma Display Panels (PDPs)
- Measuring Instruments

#### 2. General

The Toshiba TLP2368 consists of a high-output GaAlAs light-emitting diode coupled with integrated high gain, high-speed photodetectors. The TLP2368 guarantees operation at up to 125°C and on supplies from 2.7 V to 5.5 V. It is housed in the SO6 package. The TLP2368 has an internal Faraday shield that provides a guaranteed common-mode transient immunity of  $\pm 20 \text{ kV/}\mu$ s.

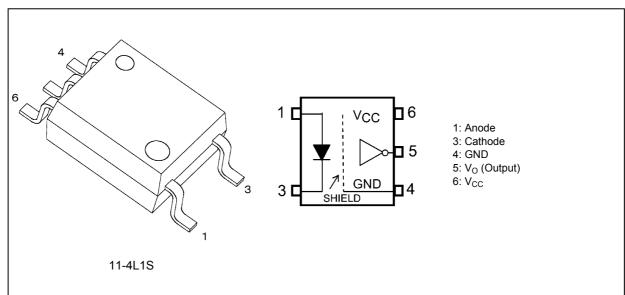
#### 3. Features

- (1) Inverter logic type (open collector output)
- (2) Package: SO6
- (3) Operating temperature: -40 to 125°C
- (4) Supply voltage: 2.7 to 5.5 V
- (5) Data transfer rate: 20 MBd (typ.) (NRZ)
- (6) Threshold input current: 5.0 mA (max)
- (7) Supply current: 4 mA (max)
- (8) Common-mode transient immunity:  $\pm 20 \text{ kV/}\mu \text{s}$  (min)
- (9) Isolation voltage: 3750 Vrms (min)
- (10) Safety standards

UL-approved: UL1577 File No.E67349

cUL-approved: CSA Component Acceptance Service No.5A, File No.E67349 VDE-approved: Option (V4) EN60747-5-5

#### 4. Packaging and Pin Configuration



Start of commercial production 2011-05 2014-04-22 Rev.5.0

#### 5. Internal Circuit

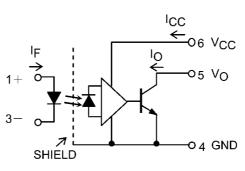


Fig. 5.1 Internal Circuit

#### 6. Principle of Operation

#### 6.1. Truth Table

Input	LED	Output
н	ON	L
L	OFF	Н

#### 6.2. Mechanical Parameters

Characteristics	Min	Unit
Creepage distances	5.0	mm
Clearance distances	5.0	
Internal isolation thickness	0.4	

#### 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25^{\circ}$ C)

	Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current		I <sub>F</sub>		25	mA
	Input forward current derating	$(T_a \ge 110^{\circ}C)$	$\Delta I_F / \Delta T_a$		-0.67	mA/°C
	Input forward current (pulsed)		I <sub>FP</sub>	(Note 1)	40	mA
	Input forward current derating (pulsed)	(T <sub>a</sub> ≥ 110°C)	$\Delta I_{FP} / \Delta T_a$		-1.0	mA/°C
	Peak transient input forward current		I <sub>FPT</sub>	(Note 2)	1	A
	Peak transient input forward current derating	$(T_a \ge 110^{\circ}C)$	$\Delta I_{FPT} / \Delta T_a$		-25	mA/°C
	Input power dissipation		PD		40	mW
	Input power dissipation derating	$(T_a \ge 110^{\circ}C)$	$\Delta P_D / \Delta T_a$		-1.0	mW/°C
	Input reverse voltage		V <sub>R</sub>		5	V
Detector	Output current		Ι <sub>Ο</sub>		25	mA
	Output voltage		Vo		6	V
	Supply voltage		V <sub>CC</sub>		6	
	Output power dissipation		Po		60	mW
	Output power dissipation derating	$(T_a \ge 110^{\circ}C)$	$\Delta P_0 / \Delta T_a$		-1.5	mW/°C
Common	Operating temperature		T <sub>opr</sub>		-40 to 125	°C
	Storage temperature		T <sub>stg</sub>		-55 to 125	
	Lead soldering temperature	(10 s)	T <sub>sol</sub>		260	
	Isolation voltage	AC, 60 s, R.H. ≤ 60%	BVS	(Note 3)	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width (PW)  $\leq$  1 ms, duty = 50%

Note 2: Pulse width (PW)  $\leq$  1  $\mu$ s, 300 pps

Note 3: This device is considered as a two-terminal device: Pins 1 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

#### 8. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Input on-state current	I <sub>F(ON)</sub>	(Note 1)	6.3	—	14	mA
Input off-state voltage	V <sub>F(OFF)</sub>		0	—	0.8	V
Supply voltage	V <sub>CC</sub>	(Note 2)	2.7	3.3/5.0	5.5	
Operating temperature	T <sub>opr</sub>	(Note 2)	-40	_	125	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this datasheet should also be considered.

Note: A ceramic capacitor (0.1 µF) should be connected between pin 6 and pin 4 to stabilize the operation of a highgain linear amplifier. Otherwise, this photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

Note 1: The rise and fall times of the input on-current should be less than 0.5  $\mu s.$ 

Note 2: Denotes the operating range, not the recommended operating condition.

# 9. Electrical Characteristics (Note) (Unless otherwise specified, $T_a$ = -40 to 125°C, $V_{CC}$ = 2.7 to 5.5 V)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input forward voltage	V <sub>F</sub>		—	I <sub>F</sub> = 10 mA, T <sub>a</sub> = 25°C	1.45	1.55	1.7	V
Input forward voltage temperature coefficient	$\Delta V_F / \Delta T_a$		—	I <sub>F</sub> = 10 mA		-2.0	—	mV/°C
Input reverse current	I <sub>R</sub>		—	V <sub>R</sub> = 5 V, T <sub>a</sub> = 25°C	_	_	10	μA
Input capacitance	Ct		—	V = 0 V, f = 1 MHz, T <sub>a</sub> = 25°C	_	60	—	pF
High-level output current	I <sub>ОН</sub>		-	V <sub>F</sub> = 0.8 V, V <sub>O</sub> = 5.5 V, V <sub>CC</sub> = 5.5 V	_	—	50	μA
				$V_F = 0.8 V, V_O = 5.5 V,$ $V_{CC} = 5.5 V, T_a = 25^{\circ}C$		—	10	
Low-level output voltage	V <sub>OL</sub>		Fig. 12.1.2	$I_F = 10 \text{ mA}$ $I_O = 13 \text{ mA} \text{ (Sinking)}$	_	0.2	0.6	V
High-level supply current	I <sub>CCH</sub>		Fig. 12.1.3	I <sub>F</sub> = 0 mA	_	1.6	4.0	mA
Low-level supply current	I <sub>CCL</sub>		Fig. 12.1.4	I <sub>F</sub> = 10 mA	_	2.0	4.0	
Threshold input current (H/L)	I <sub>FHL</sub>			$I_O$ = 13 mA (Sinking), V <sub>O</sub> < 0.6 V		1.0	5.0	

Note: All typical values are at  $T_a = 25^{\circ}C$ .

#### 10. Isolation Characteristics (Unless otherwise specified, $T_a = 25^{\circ}C$ )

Characteristics	Symbol	Note	Test Conditions	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V <sub>S</sub> = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R <sub>S</sub>	(Note 1)	$V_S$ = 500 V, R.H. $\leq$ 60%	1×10 <sup>12</sup>	10 <sup>14</sup>		Ω
Isolation voltage	BVS	(Note 1)	AC, 60 s	3750	_	—	Vrms
			AC, 1 s in oil	_	10000	—	
			DC, 60 s in oil	_	10000		Vdc

Note 1: This device is considered as a two-terminal device: Pins 1 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

#### 11. Switching Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125°C, $V_{CC} = 2.7$ to 5.5 V

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time (H/L)	t <sub>pHL</sub>	(Note 1)	Fig. 12.1.5	$I_F = 0 \rightarrow 7.5 \text{ mA}, R_L = 350 \Omega,$ C <sub>L</sub> = 15 pF	_	—	60	ns
Propagation delay time (L/H)	t <sub>pLH</sub>	(Note 1)		I <sub>F</sub> = 7.5→0 mA, R <sub>L</sub> = 350 Ω, C <sub>L</sub> = 15 pF	-	—	60	
Pulse width distortion	t <sub>pHL</sub> - t <sub>pLH</sub>	(Note 1)		$I_F$ = 7.5 mA, R <sub>L</sub> = 350 Ω, C <sub>L</sub> = 15 pF	—	—	35	
Propagation delay skew (device to device)	t <sub>psk</sub>	(Note 1), (Note 2)		$I_F$ = 7.5 mA, R <sub>L</sub> = 350 Ω, C <sub>L</sub> = 15 pF	-40	—	40	
Fall time	t <sub>f</sub>	(Note 1)		$    I_F = 0 \rightarrow 7.5 \text{ mA}, \text{ R}_L = 350 \Omega, \\ C_L = 15 \text{ pF} $	_	30	—	
Rise time	t <sub>r</sub>	(Note 1)		$    I_F = 7.5 \rightarrow 0 \text{ mA}, \text{ R}_L = 350 \Omega, \\ C_L = 15 \text{ pF} $	_	30	—	
Common-mode transient immunity at output high	CM <sub>H</sub>		Fig. 12.1.6	$V_{CM} = 1000 V_{p-p},$ $I_F = 0 mA, V_{CC} = 3.3 V / 5 V,$ $T_a = 25^{\circ}C$	±20	±25	—	kV/μs
Common-mode transient immunity at output low	CML			$V_{CM}$ = 1000 V <sub>p-p</sub> , I <sub>F</sub> = 10 mA, V <sub>CC</sub> = 3.3 V / 5 V, T <sub>a</sub> = 25°C	±20	±25	—	

Note: All typical values are at  $T_a = 25^{\circ}C$ .

Note 1: f = 5 MHz, duty = 50%, input current  $t_r = t_f = 5$  ns,  $C_L$  is approximately 15 pF which includes probe and stray wiring capacitance.

Note 2: The propagation delay skew, t<sub>psk</sub>, is equal to the magnitude of the worst-case difference in t<sub>pHL</sub> and/or t<sub>pLH</sub> that will be seen between units at the same given conditions (supply voltage, input current, temperature, etc).

#### 12. Test Circuits and Characteristics Curves

#### 12.1. Test Circuits

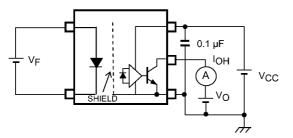
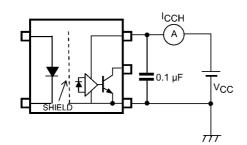


Fig. 12.1.1 IOH Test Circuit





I<sub>F</sub> = 7.5 mA (P.G.)

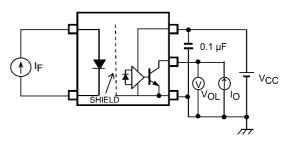


Fig. 12.1.2 V<sub>OL</sub> Test Circuit

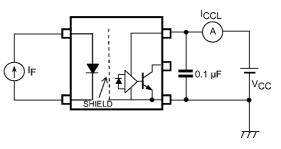
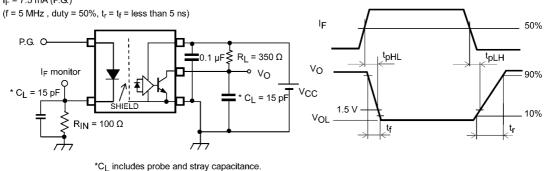


Fig. 12.1.4 I<sub>CCL</sub> Test Circuit



P.G.: Pulse generator



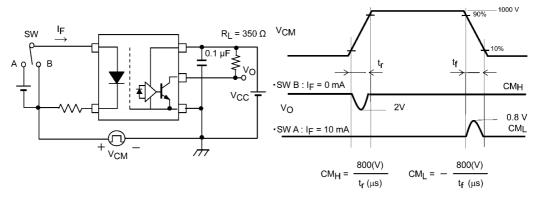
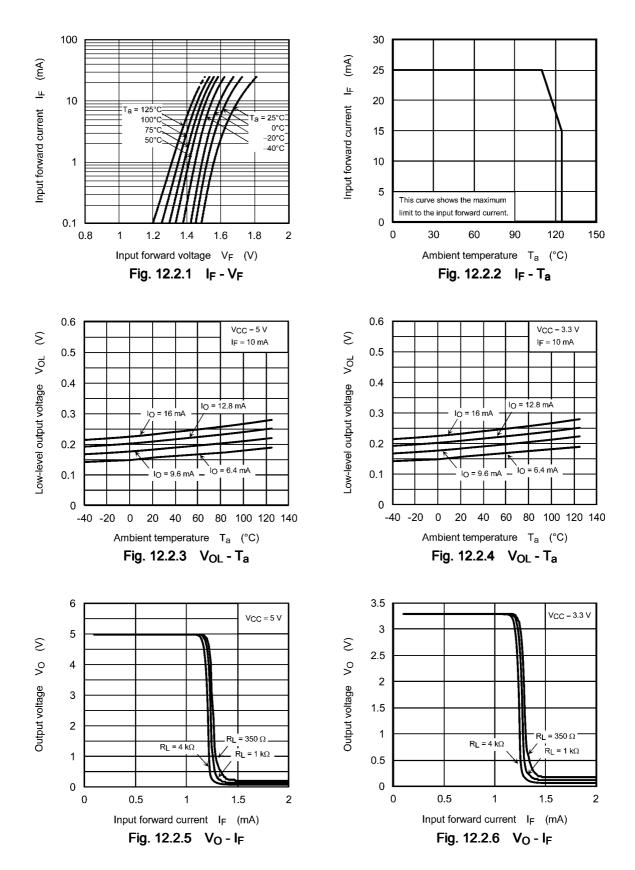
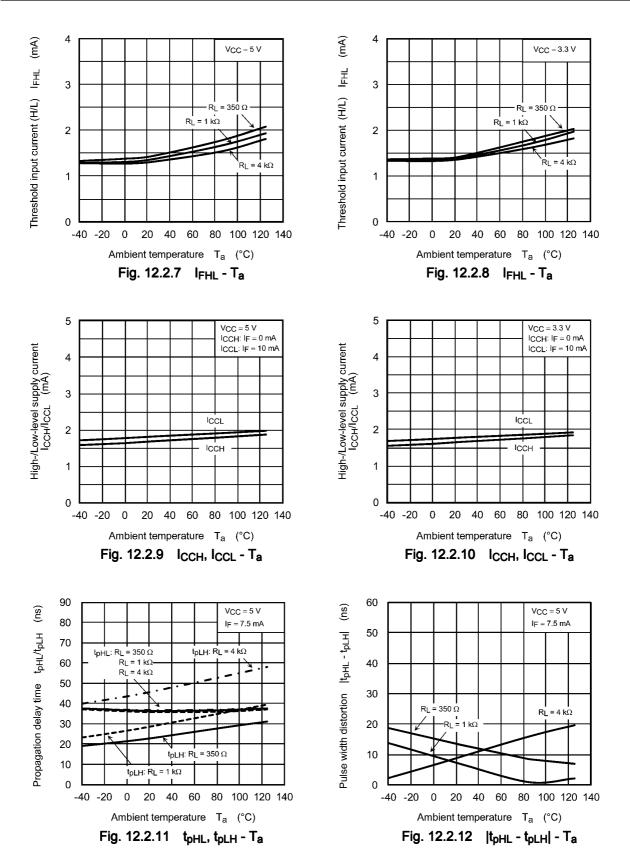
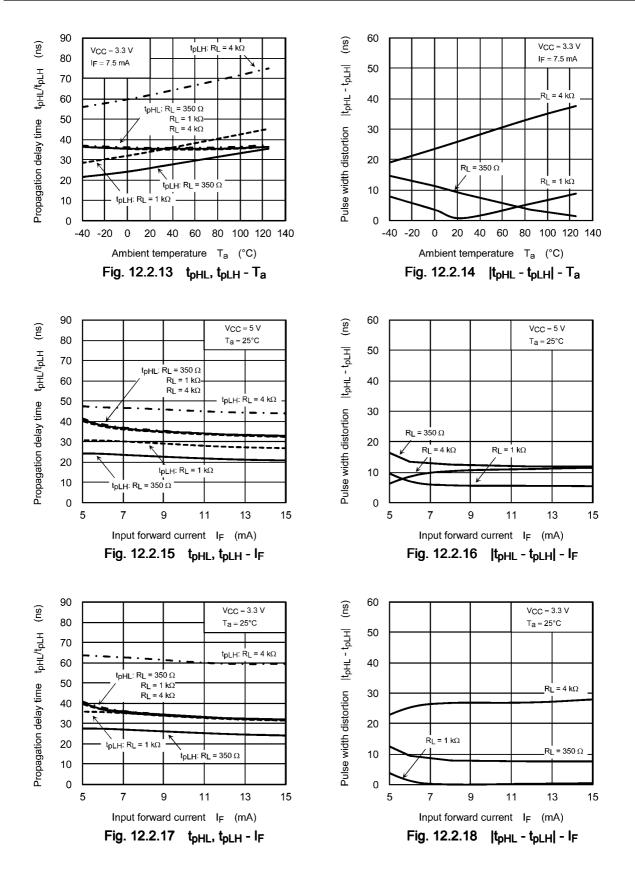


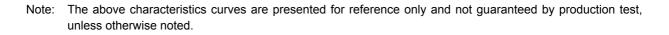
Fig. 12.1.6 Common-Mode Transient Immunity and Waveform

#### 12.2. Characteristics Curves (Note)









9

#### 13. Soldering and Storage

#### 13.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

When using soldering reflow (See Fig. 13.1.1 and 13.1.2)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

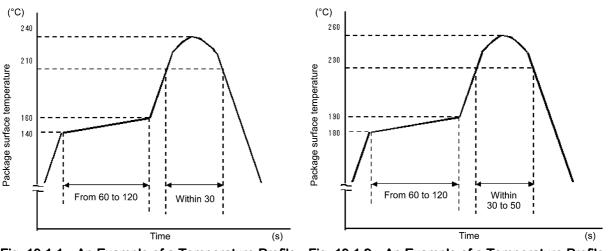
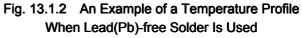


Fig. 13.1.1 An Example of a Temperature Profile When Sn-Pb Eutectic Solder Is Used



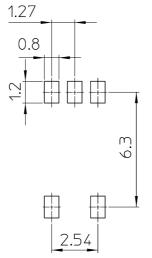
- When using soldering flow (Applicable to both eutectic solder and Lead(Pb)-Free solder) Apply preheating of 150°C for 60 to 120 seconds.
- Mounting condition of 260°C within 10 seconds is recommended.
- Flow soldering must be performed once.
- When using soldering Iron (Applicable to both eutectic solder and Lead(Pb)-Free solder)
  Complete soldering within 10 seconds for lead temperature not exceeding 260°C or within 3 seconds not exceeding 350°C

Heating by soldering iron must be done only once per lead.

#### 13.2. Precautions for General Storage

- Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- $\cdot$   $\,$  When restoring devices after removal from their packing, use anti-static containers.
- Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

#### 14. Land Pattern Dimensions for Reference Only





#### 15. Marking

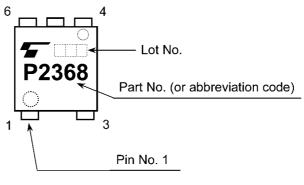


Fig. 15.1 Marking

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#### 16. EN60747-5-5 Option (V4) Specification

• Part number: TLP2368 (Note)

The following part naming conventions are used for the devices that have been qualified according to option (V4) of EN60747.

Example: TLP2368(V4-TPL,E(O

V4: EN60747 option

TPL: Tape type

E: [[G]]/RoHS COMPATIBLE (Note 1)

Note: Use TOSHIBA standard type number for safety standard application. e.g., TLP2368(V4-TPL,E(O  $\rightarrow$  TLP2368

Note 1: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

Description	Symbol	Rating	Unit
Application classification			
for rated mains voltage $\leq$ 150 Vrms for rated mains voltage $\leq$ 300 Vrms		I-I∨ I-III	-
Climatic classification		40 / 125 / 21	_
Pollution degree		2	_
Maximum operating insulation voltage	VIORM	707	Vpeak
Input to output test voltage, Method A $V_{pr}$ = 1.6 × V <sub>IORM</sub> , type and sample test $t_p$ = 10 s, partial discharge < 5 pC	V <sub>pr</sub>	1131	Vpeak
Input to output test voltage, Method B $V_{pr} = 1.875 \times V_{IORM}$ , 100 % production test $t_p = 1 s$ , partial discharge < 5 pC	V <sub>pr</sub>	1325	Vpeak
Highest permissible overvoltage (transient overvoltage, t <sub>pr</sub> = 60 s)	V <sub>TR</sub>	6000	Vpeak
Safety limiting values (max. permissible ratings in case of fault, also refer to thermal derating curve) current (input current I <sub>F</sub> , P <sub>so</sub> = 0) power (output or total power dissipation) temperature	I <sub>si</sub> P <sub>so</sub> Ts	250 400 150	mA mW °C
Insulation resistance $V_{IO} = 500 \text{ V}, \text{ T}_a = 25 \text{ °C}$ $V_{IO} = 500 \text{ V}, \text{ T}_a = 100 \text{ °C}$ $V_{IO} = 500 \text{ V}, \text{ T}_a = \text{ T}_s$	R <sub>si</sub>	≥ 10 <sup>12</sup> ≥ 10 <sup>11</sup> ≥ 10 <sup>9</sup>	Ω

Fig. 16.1	EN60747	Isolation	Characteristics
1 19. 10.1		100101011	Onaraoteriotico

Minimum creepage distance	Cr	5.0 mm
Minimum clearance	CI	5.0 mm
Minimum insulation thickness	ti	0.4 mm
Comparative tracking index	CTI	175

Fig. 16.2	Insulation	<b>Related</b> S	Specifications

- Note: If a printed circuit is incorporated, the creepage distance and clearance may be reduced below this value. (e. g., at a standard distance between soldering eye centers of 3.5 mm). If this is not permissible, the user shall take suitable measures.
- Note: This photocoupler is suitable for **safe electrical isolation** only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits.

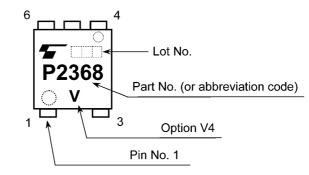
VDE test sign : Marking on product for EN60747

V

: Marking on packing for EN60747



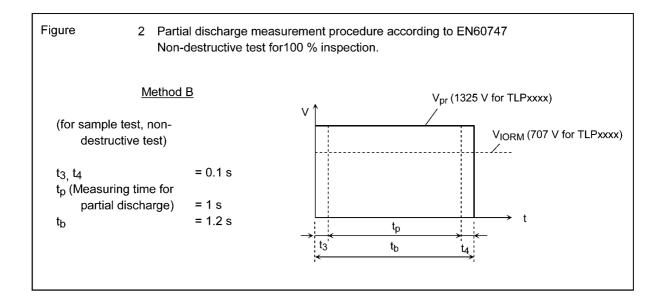
Marking Example : TLP2368

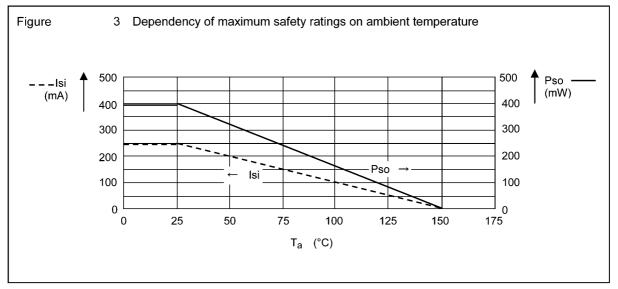




Note: The above marking is applied to the photocouplers that have been qualified according to option (V4) of EN60747.

5	-	surement procedure according to EN60747 alification and sampling tests.
Method	<u>A</u>	V <sub>INITIAL</sub> (6 kV)
(for type and sampling t destructive tests)	ests,	$V \downarrow V \downarrow V_{pr}$ (1131 V for TLPxxxx)
t <sub>1</sub> , t <sub>2</sub>	= 1 to 10 s	V <sub>IORM</sub> (707 V for TLPxxxx)
t3, t4	= 1 s	
t <sub>p</sub> (Measuring time for		
partial discharge)	= 10 s	$0 \xrightarrow{\mu} t \xrightarrow{t} t$
t <sub>b</sub>	= 12 s	$t_3$ $t_p$ $t_4$
t <sub>ini</sub>	= 60 s	t <sub>1</sub> t <sub>ini</sub> t <sub>2</sub> t <sub>b</sub>





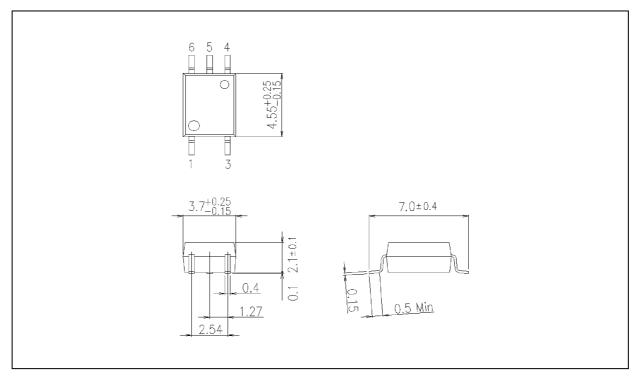
#### Fig. 16.4 Measurement Procedure



#### Package Dimensions

TLP2368

Unit: mm



#### Weight: 0.08 g (typ.)



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